# OTA

ISSUED BY Shenzhen BALUN Technology Co., Ltd.



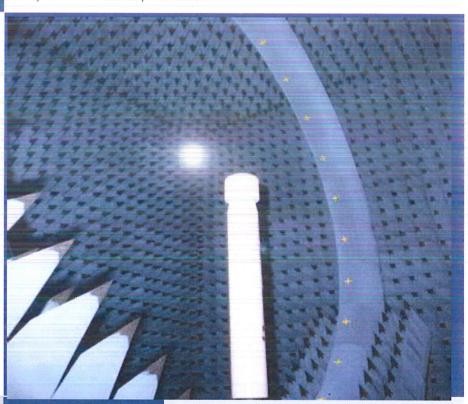
FOR

#### kb module

ISSUED TO SHENZH BOYCHUANG TECHNOLOGY CO, LTD

TESTREPORT

Room 407-408, skyworth semiconductor building, no.18, gaoxin south 4th road, nanshan district, shenzhen



Tested by: Zong Liyao

Date Wow of Your

Approved by:

Wei Yanguan
(Chief Engineer)

Date Zong Liyao

Report No: EUT Name: Model Name: Brand Name: Test Standard:

kb module HS6200 N/A

BL-SZ20A0582-901

IEEE149-1979 Gain: -0.86 (dBi)

Efficiency: 30%

Test Date: Date of Issue:

Maximum:

Oct. 30, 2020 Nov. 03, 2020

NOTE: This test report of test results only related to the testing samples, which can be duplicated completely for the legal use with the approval of applicant; it shall not be reproduced except in full, without the written approval of Shenzhen BALUN Technology Co., Ltd. Any objections should be rais within thirty days from the date of issue. To validate the report, please visit BALUN website.



#### **Revision History**

Version Rev. 01

Issue Date

Nov. 03, 2020

Revisions

Initial Issue

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#### 1 Administrative Data (GENERAL INFORMATION)

#### 1.1 Identification of the Testing Laboratory

Company Name	Shenzhen BALUN Technology Co., Ltd.
Address	Block B, 1st FL, Baisha Science and Technology Park, Shahe Xi Road,
	Nanshan District, Shenzhen, Guangdong Province, P. R. China
Phone Number	+86 755 6685 0100

#### 1.2 Identification of the Responsible Testing Location

Test Location	Shenzhen BALUN Technology Co., Ltd.	
Addross	Block B, 1st FL, Baisha Science and Technology Park, Shahe Xi Road,	
Address	Nanshan District, Shenzhen, Guangdong Province, P. R. China	
	The laboratory is a testing organization accredited by China National	
Accreditation Certificate	Accreditation Service for Conformity Assessment (CNAS) according to	
	ISO/IEC 17025. The accreditation certificate number is L6791.	
	The laboratory is a testing organization accredited by China Metrology	
	Accreditation (CMA). The accreditation certificate number is	
	2017192290Z.	
D	All measurement facilities used to collect the measurement data are	
	located at Block B, FL 1, Baisha Science and Technology Park, Shahe	
Description	Xi Road, Nanshan District, Shenzhen, Guangdong Province, P. R.	
	China 518055	

#### 1.3 Laboratory Condition

Ambient Temperature	19°C to 25°C
Ambient Relative Humidity	45% to 55%
Ambient Pressure	100 kPa to 102 kPa

#### 1.4 Announce

- (1) The test report reference to the report template version v2.2.
- (2) The test report is invalid if not marked with the signatures of the persons responsible for preparing and approving the test report.
- (3) The test report is invalid if there is any evidence and/or falsification.
- (4) The results documented in this report apply only to the tested sample, under the conditions and modes of operation as described herein.
- (5) This document may not be altered or revised in any way unless done so by BALUN and all revisions are duly noted in the revisions section.
- (6) Content of the test report, in part or in full, cannot be used for publicity and/or promotional purposes without prior written approval from the laboratory.
- (7) The laboratory is only responsible for the data released by the laboratory, except for the part provided by the applicant.



#### **2 PRODUCT INFORMATION**

## 2.1 Applicant Information

Applicant	SHENZH BOYCHUANG TECHNOLOGY CO, LTD
Address	Room 407-408, skyworth semiconductor building, no.18, gaoxin south
Address	4th road, nanshan district, shenzhen
Contact Person	QIAN.YI
Telephone Number	Mobile: 13612864217
E-mail Address	qian.yi@onmicro.com.cn

#### 2.2 Manufacturer Information

Manufacturer	SHENZH BOYCHUANG TECHNOLOGY CO, LTD	
Address	Room 407-408, skyworth semiconductor building, no.18, gaoxin south	
Address	4th road, nanshan district, shenzhen	

## 2.3 Factory Information

Factory	N/A
Address	N/A

## 2.4 General Description for Equipment under Test (EUT)

EUT Name	kb module
Model Name Under Test	HS6200
Antenna Type	PCB Antenna
Dimensions	15mm*5mm

## 2.5 Ancillary Equipment

N/A

#### 2.6 Technical Information

Frequency Range	2402MHz ~2480MHz
Test Frequencies 2402MHz, 2440MHz, 2480MHz	



#### **3 SUMMARY OF TEST RESULTS**

#### 3.1 Test Standards

No.	Identity	Document Title
1	IEEE149-1979	IEEE Standard Test Procedures for Antennas

#### 3.2 Test Verdict

Report Section	Description	Remark
ANNEX A.1	Gain and Efficiency	

#### 3.3 Test Uncertainty

The uncertainty is calculated using the methods suggested in the "Guide to the Expression of Uncertainty in Measurement" (GUM) published by ISO.

Item	Uncertainty
Gain	$\pm$ 0.5dB



## **4 GENERAL TEST CONFIGURATIONS**

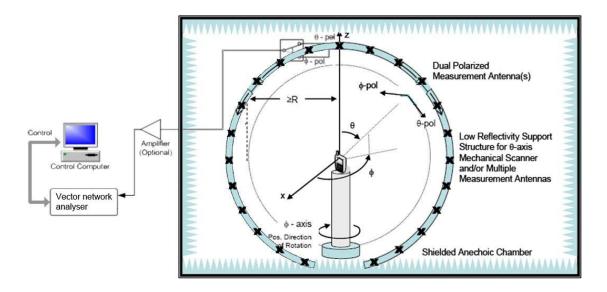
#### 4.1 Test Condition

	Selected Values During Tests				
Environment Parameter	Ambient Pressure (KPa)	Temperature(°C)	Voltage	Relative Humidity (%)	
Normal Temperature, Normal Voltage (NTNV)	100 to 102	19 to 25	N/A	45 to 55	

#### 4.2 Test Equipment List

Description	Manufacturer	Model	Serial No.	Cal. Date	Cal. Due
Vector Network	A gilont	E5071C	MY46103472	2020.02.19	2021.02.18
Analyzer	Agilent	E307 IC	W1146103472	2020.02.19	2021.02.10
SG24 Multi-probe			1101855-		
Antenna Measurement	SATIMO	SG24-L		2020.06.22	2021.06.21
System			0001		

#### 4.3 Test Setup





## **ANNEX A TEST RESULTS**

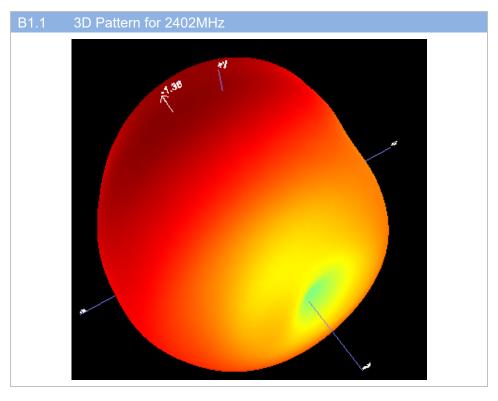
# A.1 Gain and Efficiency

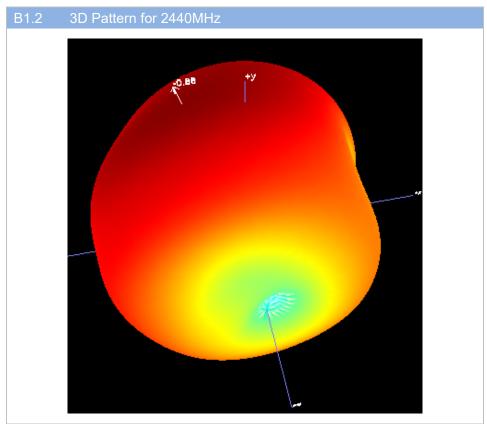
Frequency	Gain (dBi)	Efficiency (%)	
2402MHz	-1.36	25	
2440MHz	-0.86	28	
2480MHz	-0.91	30	



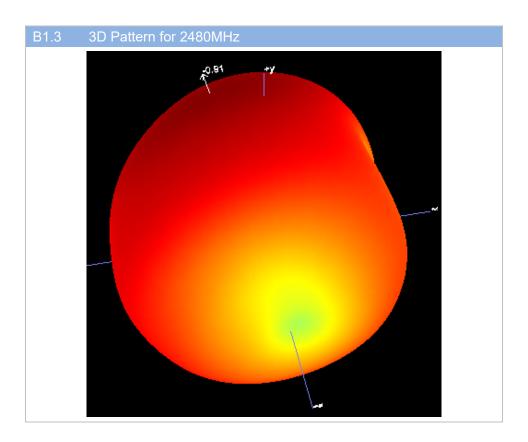
## **ANNEX B RADIATION PATTERN**

#### **B.1 3D Pattern**



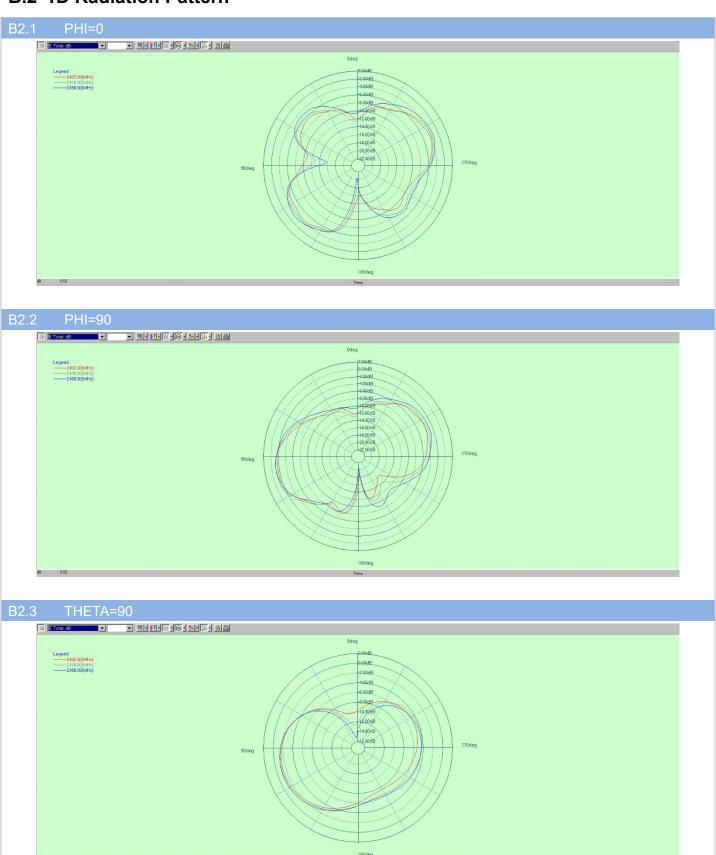






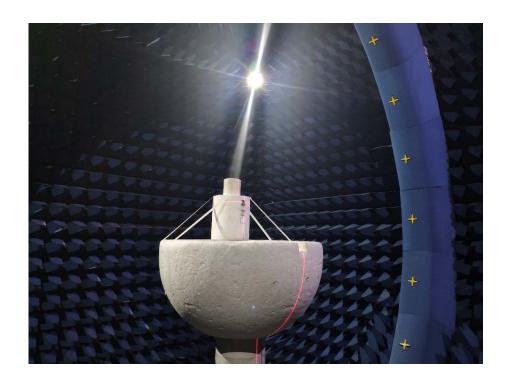


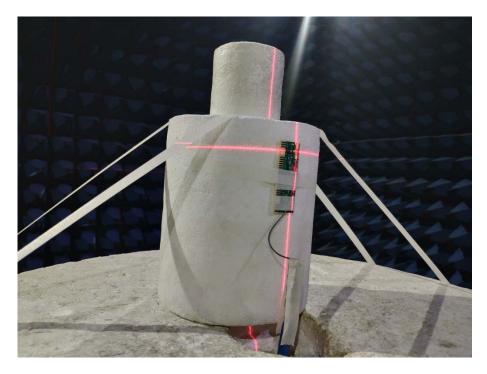
#### **B.2 1D Radiation Pattern**





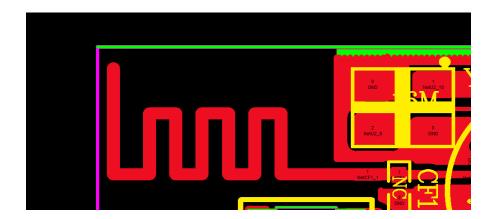
# ANNEX C TEST SETUP PHOTO







## ANNEX D EUT PHOTO



--END OF REPORT--